2 OUTPUT PCI-EXPRESS GEN1 CLOCK SOURCE

IDT5V41129

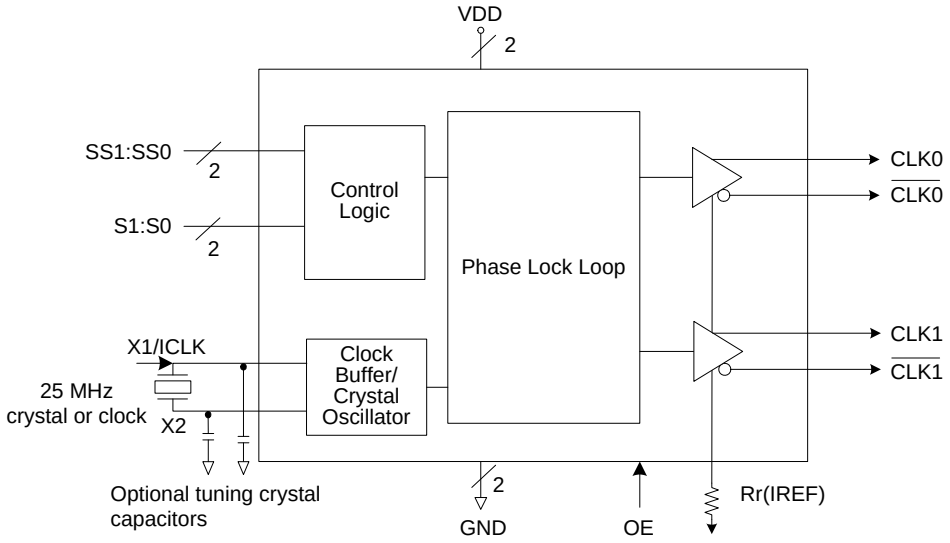
Description

The IDT5V41129 is a spread spectrum clock generator that supports PCI-Express Gen1 and Ethernet requirements. The device is used for PC or embedded systems to substantially reduce electromagnetic interference (EMI). The device provides two differential (HCSL) spread spectrum outputs. The spread type and amount are configured via select pin. Using IDT's patented Phase-Locked Loop (PLL) techniques, the device takes a 25 MHz crystal input and produces two pairs of differential outputs at 25 MHz, 100 MHz, 125 MHz or 200 MHz clock frequencies for HCSL, and 25 MHz or 100 MHz for LVDS.

Features

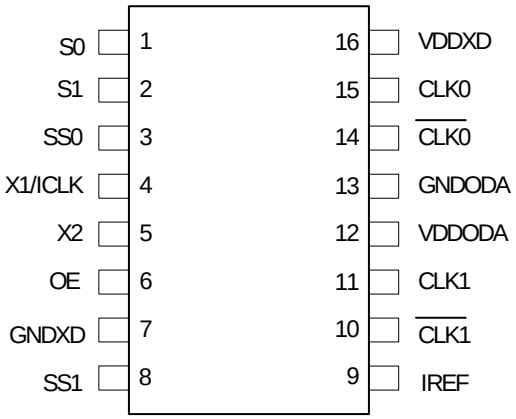
- Packaged in 16-pin TSSOP
- RoHS 5 (green) or RoHS 6 (green and lead free) compliant packaging
- Supports HCSL or LVDS output levels
- Operating voltage of 3.3 V
- Input frequency of 25 MHz
- Jitter 60 ps (cycle-to-cycle)
- Spread Spectrum capability
- Industrial and commercial temperature ranges
- **For PCIe Gen2 applications, see the 5V41065**
- **For PCIe Gen3 applications, see the 5V41235**

Block Diagram



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Pin Assignment



16-pin (173 mil) TSSOP

Output Select Table 1 (MHz)

S1	S0	CLK(1:0), CLK(1:0)
0	0	25M
0	1	100M
1	0	125M
1	1	200M

Spread Selection Table 2

SS1	SS0	Spread%
0	0	No Spread
0	1	Down -0.5
1	0	Down -0.75
1	1	No Spread

Pin Descriptions

Pin Number	Pin Name	Pin Type	Pin Description
1	S0	Input	Select pin 0. See Table1. Internal pull-up resistor.
2	S1	Input	Select pin 1. See Table 1. Internal pull-up resistor.
3	SS0	Input	Spread Select pin 0. See Table 2. Internal pull-up resistor.
4	X1/ICLK	Input	Crystal or clock input. Connect to a 25 MHz crystal or single ended clock.
5	X2	Output	Crystal connection. Leave unconnected for clock input.
6	OE	Input	Output enable. Tri-states outputs and device is not shut down. Internal pull-up resistor.
7	GNDXD	Power	Connect to ground.
8	SS1	Input	Spread Select pin 1. See Table 2. Internal pull-up resistor.
9	IREF	Output	Precision resistor attached to this pin is connected to the internal current reference.
10	CLK1	Output	HCSL complimentary clock output 1.
11	CLK1	Output	HCSL true clock output 1.
12	VDDODA	Power	Connect to voltage supply +3.3 V for output driver and analog circuits
13	GNDODA	Power	Connect to ground.
14	CLK0	Output	HCSL complimentary clock output 0.
15	CLK0	Output	HCSL true clock output 0.
16	VDDXD	Power	Connect to voltage supply +3.3 V for crystal oscillator and digital circuit.

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Applications Information

External Components

A minimum number of external components are required for proper operation.

Decoupling Capacitors

Decoupling capacitors of 0.01 μF should be connected between each VDD pin and the ground plane, as close to the VDD pin as possible. Do not share ground vias between components. Route power from power source through the capacitor pad and then into ICS pin.

Crystal

A 25 MHz fundamental mode parallel resonant crystal should be used. This crystal must have less than 300 ppm of error across temperature in order for the IDT5V41129 to meet PCI Express specifications.

Crystal Capacitors

Crystal capacitors are connected from pins X1 to ground and X2 to ground to optimize the accuracy of the output frequency.

C_L= Crystal's load capacitance in pF

Crystal Capacitors (pF) = (C_L- 8) * 2

For example, for a crystal with a 16 pF load cap, each external crystal cap would be 16 pF. (16-8)*2=16.

Current Source (Iref) Reference Resistor - R_R

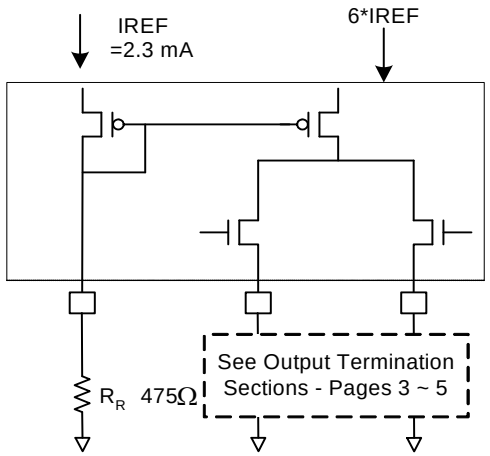
If board target trace impedance (Z) is 50Ω, then R_R = 475Ω (1%), providing IREF of 2.32 mA. The output current (I_{OH}) is equal to 6*IREF.

Output Termination

The PCI-Express differential clock outputs of the IDT5V41129 are open source drivers and require an external series resistor and a resistor to ground. These resistor values and their allowable locations are shown in detail in the **PCI-Express Layout Guidelines** section.

The IDT5V41129 can also be configured for LVDS compatible voltage levels. See the **LVDS Compatible Layout Guidelines** section.

Output Structures



General PCB Layout Recommendations

For optimum device performance and lowest output phase noise, the following guidelines should be observed.

1. Each 0.01μF decoupling capacitor should be mounted on the component side of the board as close to the VDD pin as possible.

2. No vias should be used between decoupling capacitor and VDD pin.

3. The PCB trace to VDD pin should be kept as short as possible, as should the PCB trace to the ground via. Distance of the ferrite bead and bulk decoupling from the device is less critical.

4. An optimum layout is one with all components on the same side of the board, minimizing vias through other signal layers (any ferrite beads and bulk decoupling capacitors can be mounted on the back). Other signal traces should be routed away from the IDT5V41129.This includes signal traces just underneath the device, or on layers adjacent to the ground plane layer used by the device.

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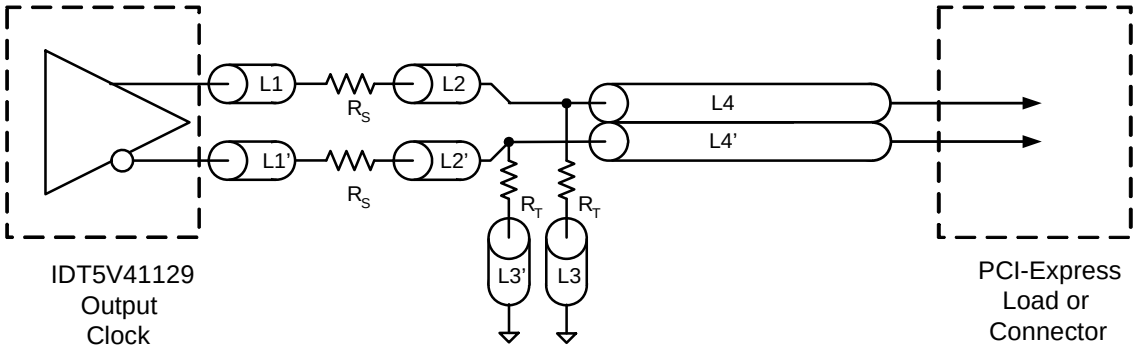
PCI-Express Layout Guidelines

Common Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, Route as non-coupled 50 ohm trace.	0.5 max	inch
L2 length, Route as non-coupled 50 ohm trace.	0.2 max	inch
L3 length, Route as non-coupled 50 ohm trace.	0.2 max	inch
R_S	33	ohm
R_T	49.9	ohm

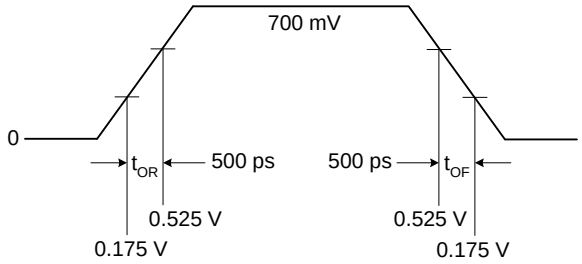
Differential Routing on a Single PCB	Dimension or Value	Unit
L4 length, Route as coupled **microstrip** 100 ohm differential trace.	2 min to 16 max	inch
L4 length, Route as coupled **stripline** 100 ohm differential trace.	1.8 min to 14.4 max	inch

Differential Routing to a PCI Express Connector	Dimension or Value	Unit
L4 length, Route as coupled **microstrip** 100 ohm differential trace.	0.25 to 14 max	inch
L4 length, Route as coupled **stripline** 100 ohm differential trace.	0.225 min to 12.6 max	inch

PCI-Express Device Routing



Typical PCI-Express (HCSL) Waveform

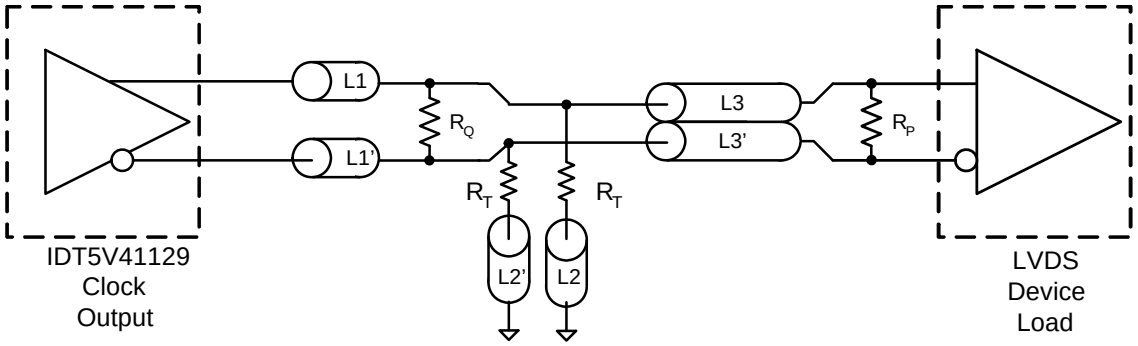


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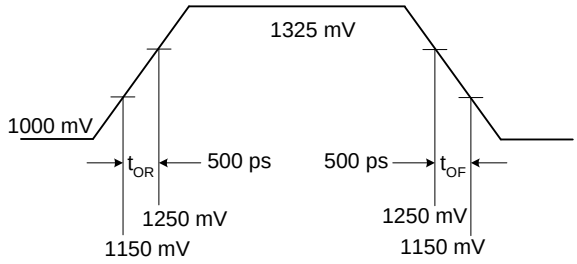
LVDS Compatible Layout Guidelines

LVDS Recommendations for Differential Routing	Dimension or Value	Unit
L1 length, Route as non-coupled 50 ohm trace.	0.5 max	inch
L2 length, Route as non-coupled 50 ohm trace.	0.2 max	inch
R_P	100	ohm
R_Q	100	ohm
R_T	150	ohm

LVDS Device Routing



Typical LVDS Waveform



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Absolute Maximum Ratings

Stresses above the ratings listed below can cause permanent damage to the IDT5V41129. These ratings are stress ratings only. Functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods can affect product reliability. Electrical parameters are guaranteed only over the recommended operating temperature range.

Item	Rating
Supply Voltage, VDDXD, VDDODA	7 V
All Inputs and Outputs	-0.5 V to VDD+0.5 V
Ambient Operating Temperature (commercial)	0 to +70°C
Ambient Operating Temperature (industrial)	-40 to +85°C
Storage Temperature	-65 to +150°C
Junction Temperature	125°C
Soldering Temperature	260°C
ESD Protection (Input)	2000 V min. (HBM)

DC Electrical Characteristics

Unless stated otherwise, **VDD = 3.3 V ±10%**, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Supply Voltage	V		2.97	3.3	3.63	V
Input High Voltage[1]	V_{IH}	S0, S1, OE, ICLK, SS0, SS1	2.0		VDD +0.3	V
Input Low Voltage[1]	V_{IL}	S0, S1, OE, ICLK, SS0, SS1	VSS-0.3		0.8	V
Input Leakage Current[2]	I_{IL}	0 < Vin < VDD	-5		5	µA
Operating Supply Current	I_{DD}	50Ω, 2 pF			78	mA
	I_{DDOE}	OE =Low			44	mA
Input Capacitance	C_{IN}	Input pin capacitance			7	pF
Output Capacitance	C_{OUT}	Output pin capacitance			6	pF
Pin Inductance	L_{PIN}				5	nH
Output Resistance	R_{OUT}	CLK outputs	3.0			kΩ
Pull-up Resistor	R_{PU}	S0, S1, OE, SS0, SS1		100		kΩ

1. Single edge is monotonic when transitioning through region.
2. Inputs with pull-ups/-downs are not included.

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AC Electrical Characteristics - CLK0/CLK1, $\overline{CLK0/CLK1}$

Unless stated otherwise, **VDD=3.3 V ±10%**, Ambient Temperature -40 to +85°C

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Input Frequency				25		MHz
Output Frequency		HCSL termination	25		200	MHz
		LVDS termination	25		100	MHz
Output High Voltage[1,2]	V_{OH}	HCSL	660	700	850	mV
Output Low Voltage[1,2]	V_{OL}	HCSL	-150	0	27	mV
Crossing Point Voltage[1,2]		Absolute	250	350	550	mV
Crossing Point Voltage[1,2,4]		Variation over all edges			140	mV
Jitter, Cycle-to-Cycle[1,3]				60	100	ps
Frequency Synthesis Error		All outputs		0		ppm
Modulation Frequency		Spread spectrum	30	31.5	33	kHz
Rise Time[1,2]	t_{OR}	From 0.175 V to 0.525 V	175	332	700	ps
Fall Time[1,2]	t_{OF}	From 0.525 V to 0.175 V	175	344	700	ps
Rise/Fall Time Variation[1,2]					125	ps
Output to Output Skew					50	ps
Duty Cycle[1,3]			45		55	%
Output Enable Time[5]		All outputs		10	12	µs
Output Disable Time[5]		All outputs		10	12	µs
Stabilization Time	t_{STABLE}	From power-up VDD=3.3 V		3.0	3.5	ms
Spread Spectrum Transition Time	t_{SPREAD}	Stabilization time after spread spectrum changes		3.0	3.5	ms

Note 1: Test setup is R_L=50 ohms with 2 pF, Rr = 475Ω (1%).

Note 2: Measurement taken from a single-ended waveform.

Note 3: Measurement taken from a differential waveform.

Note 4: Measured at the crossing point where instantaneous voltages of both CLK and $\overline{CLK}$ are equal.

Note 5: CLK pins are tri-stated when OE is low asserted. CLK is driven differential when OE is high.

Electrical Characteristics - Differential Phase Jitter

Parameter	Symbol	Conditions	Min	Typ	Max	Units	Notes
Jitter, Phase	tjphasePLL	PCIe Gen 1	-	-	86	ps (p-p)	1, 2

Note 1: Guaranteed by design and characterization, not 100% tested in production.

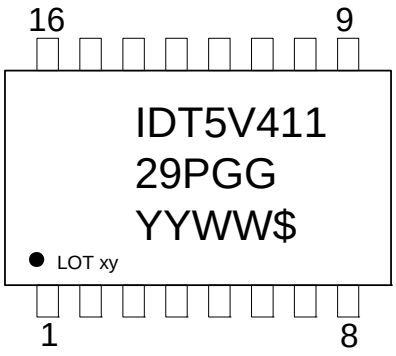
Note 2: See http://www.pcisig.com for complete specs.

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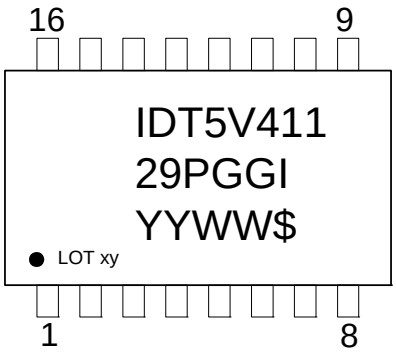
Thermal Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Thermal Resistance Junction to Ambient	θ_{JA}	Still air		78		°C/W
	θ_{JA}	1 m/s air flow		70		°C/W
	θ_{JA}	3 m/s air flow		68		°C/W
Thermal Resistance Junction to Case	θ_{JC}			37		°C/W

Marking Diagram (5V41129PGG)



Marking Diagram (5V41129PGGI)



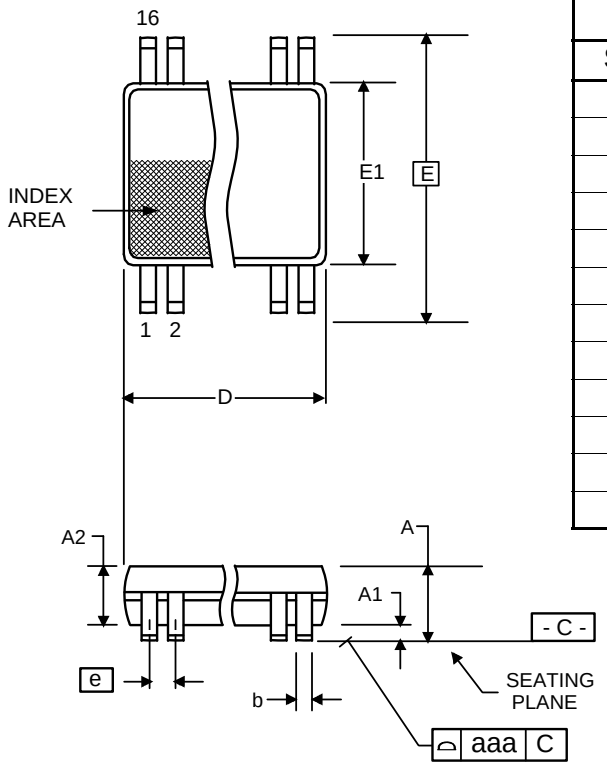
Notes:

1. Line 1 and 2: IDT part number.
2. Line 3: YYWW – Date code; $ – Assembly location.
3. “G” after the two-letter package code designates RoHS compliant package.
4. “I” at the end of part number indicates industrial temperature range.

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Package Outline and Package Dimensions (16-pin TSSOP, 173 Mil. Narrow Body)

Package dimensions are kept current with JEDEC Publication No. 95



	Millimeters		Inches*	
Symbol	**Min**	**Max**	**Min**	**Max**
A	--	1.20	--	0.047
A1	0.05	0.15	0.002	0.006
A2	0.80	1.05	0.032	0.041
b	0.19	0.30	0.007	0.012
C	0.09	0.20	0.0035	0.008
D	4.90	5.1	0.193	0.201
E	6.40 BASIC		0.252 BASIC	
E1	4.30	4.50	0.169	0.177
e	0.65 Basic		0.0256 Basic	
L	0.45	0.75	0.018	0.030
a	0°	8°	0°	8°
aaa	--	0.10	--	0.004

Ordering Information

Part / Order Number	Marking	Shipping Packaging	Package	Temperature
5V41129PGG	see page 8	Tubes	16-pin TSSOP	0 to +70° C
5V41129PGG8		Tape and Reel	16-pin TSSOP	0 to +70° C
5V41129PGGI		Tubes	16-pin TSSOP	-40 to +85° C
5V41129PGGI8		Tape and Reel	16-pin TSSOP	-40 to +85° C

"G" after the two-letter package code are the Pb-Free configuration and are RoHS compliant.

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Revision History

Rev.	Date	Originator	Description of Change
C	10/30/12	D. Chan	Updated device top-side markings per latest ProdBuilder info.
D	02/03/14	RDW	Typo for part number in Termination drawings. Moved to final.

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